National Semiconductor is now part of

Texas Instruments.

Search http://www.ti.com/ for the latest technical

information and details on our current products and services.

National Semiconductor

May 2006

LMC555
CMOS Timer

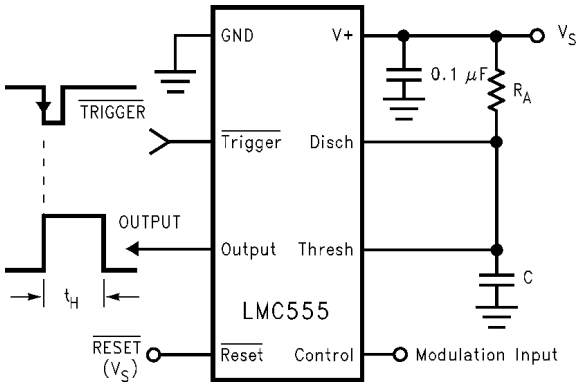
General Description

The LMC555 is a CMOS version of the industry standard 555 series general purpose timers. In addition to the standard package (SOIC, MSOP, and MDIP) the LMC555 is also available in a chip sized package (8 Bump micro SMD) using National's micro SMD package technology. The LMC555 offers the same capability of generating accurate time delays and frequencies as the LM555 but with much lower power dissipation and supply current spikes. When operated as a one-shot, the time delay is precisely controlled by a single external resistor and capacitor. In the stable mode the oscillation frequency and duty cycle are accurately set by two external resistors and one capacitor. The use of National Semiconductor's LMCMOS™ process extends both the frequency range and low supply capability.

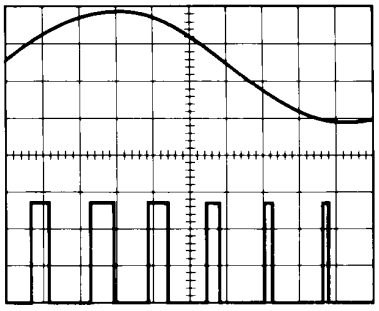
Features

- Less than 1 mW typical power dissipation at 5V supply
- 3 MHz astable frequency capability
- 1.5V supply operating voltage guaranteed
- Output fully compatible with TTL and CMOS logic at 5V supply
- Tested to −10 mA, +50 mA output current levels
- Reduced supply current spikes during output transitions
- Extremely low reset, trigger, and threshold currents
- Excellent temperature stability
- Pin-for-pin compatible with 555 series of timers
- Available in 8-pin MSOP Package and 8-Bump micro SMD package

Pulse Width Modulator



00866920



00866915

Ordering Information

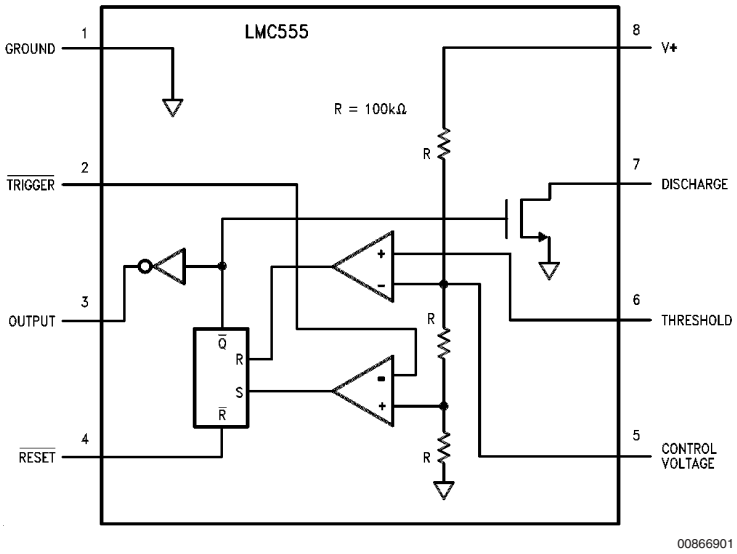
Package	Temperature Range	Package Marking	Transport Media	NSC Drawing
	Industrial −40˚C to +85˚C			
8-Pin Small Outline (SO)	LMC555CM	LMC555CM	Rails	M08A
	LMC555CMX		2.5k Units Tape and Reel	
8-Pin Mini Small Outline (MSOP)	LMC555CMM	ZC5	1k Units Tape and Reel	MUA08A
	LMC555CMMX		3.5k Units Tape and Reel	
8-Pin Molded Dip (MDIP)	LMC555CN	LMC555CN	Rails	N08E
8-Bump micro SMD	LMC555CBP	F1	250 Units Tape and Reel	BPA08EFB
	LMC555CBPX		3k Units Tape and Reel	
8-Bump micro SMD NOPB	LMC555CTP	F02	250 Units Tape and Reel	TPA08EFA
	LMC555CTPX		3k Units Tape and Reel	

Note: See Mil-datasheet MNLMC555-X for specifications on the military device LMC555J/883.

LMCMOS™ is a trademark of National Semiconductor Corp.

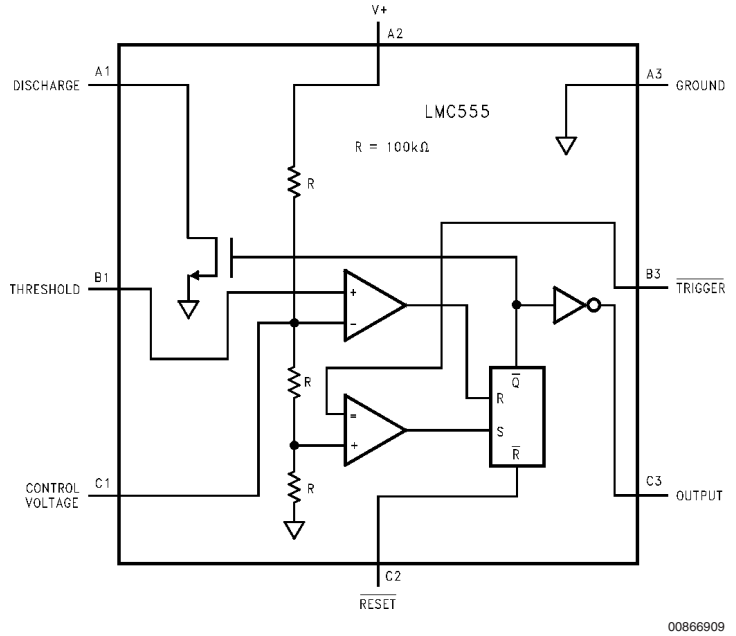
Connection Diagrams

8-Pin SOIC, MSOP, MDIP



Top View

8-Bump micro SMD



Top View
(Bump Side Down)

Absolute Maximum Ratings (Notes 2, 3)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

Supply Voltage, V^+	15V
Input Voltages, V_{TRIG}, V_{RES}, V_{CTRL}, V_{THRESH}	−0.3V to V_S + 0.3V
Output Voltages, V_O, V_{DIS}	15V
Output Current I_O, I_{DIS}	100 mA
Storage Temperature Range	−65˚C to +150˚C
Soldering Information	
MDIP Soldering (10 seconds)	260˚C
SOIC, MSOP Vapor Phase (60 sec)	215˚C
SOIC, MSOP Infrared (15 sec)	220˚C

Note: See AN-450 "Surface Mounting Methods and Their Effect on Product Reliability" for other methods of soldering surface mount devices.

Thermal Resistance (θ_{JA}) (Note 2)	
SO, 8-Pin Small Outline	169˚C/W
MSOP, 8-Pin Mini Small Outline	225˚C/W
MDIP, 8-Pin Molded Dip	111˚C/W
8-Bump micro SMD	220˚C/W
Maximum Allowable Power Dissipation @25˚C	
MDIP-8	1126 mW
SO-8	740 mW
MSOP-8	555 mW
8 Bump micro SMD	568 mW

Operating Ratings (Notes 2, 3)

Termperature Range	−40˚C to +85˚C

Electrical Characteristics (Notes 1, 2)

Test Circuit, T = 25˚C, all switches open, $\overline{\text{RESET}}$ to V_S unless otherwise noted

Symbol	Parameter	Conditions	Min	Typ	Max	Units (Limits)
I_S	Supply Current	V_S = 1.5V		50	150	µA
		V_S = 5V		100	250	
		V_S = 12V		150	400	
V_{CTRL}	Control Voltage	V_S = 1.5V	0.8	1.0	1.2	V
		V_S = 5V	2.9	3.3	3.8	
		V_S = 12V	7.4	8.0	8.6	
V_{DIS}	Discharge Saturation Voltage	V_S = 1.5V, I_{DIS} = 1 mA		75	150	mV
		V_S = 5V, I_{DIS} = 10 mA		150	300	
V_{OL}	Output Voltage (Low)	V_S = 1.5V, I_O = 1 mA		0.2	0.4	V
		V_S = 5V, I_O = 8 mA		0.3	0.6	
		V_S = 12V, I_O = 50 mA		1.0	2.0	
V_{OH}	Output Voltage (High)	V_S = 1.5V, I_O = −0.25 mA	1.0	1.25		V
		V_S = 5V, I_O = −2 mA	4.4	4.7		
		V_S = 12V, I_O = −10 mA	10.5	11.3		
V_{TRIG}	Trigger Voltage	V_S = 1.5V	0.4	0.5	0.6	V
		V_S = 12V	3.7	4.0	4.3	
I_{TRIG}	Trigger Current	V_S = 5V		10		pA
V_{RES}	Reset Voltage	V_S = 1.5V (Note 4)	0.4	0.7	1.0	V
		V_S = 12V	0.4	0.75	1.1	
I_{RES}	Reset Current	V_S = 5V		10		pA
I_{THRESH}	Threshold Current	V_S = 5V		10		pA
I_{DIS}	Discharge Leakage	V_S = 12V		1.0	100	nA
t	Timing Accuracy	SW 2, 4 Closed				ms
		V_S = 1.5V	0.9	1.1	1.25	
		V_S = 5V	1.0	1.1	1.20	
		V_S = 12V	1.0	1.1	1.25	
$\Delta t/\Delta V_S$	Timing Shift with Supply	V_S = 5V ± 1V		0.3		%/V

Electrical Characteristics (Notes 1, 2)

Test Circuit, T = 25˚C, all switches open, $\overline{\text{RESET}}$ to V_S unless otherwise noted (Continued)

Symbol	Parameter	Conditions	Min	Typ	Max	Units (Limits)
$\Delta t/\Delta T$	Timing Shift with Temperature	V_S = 5V −40˚C ≤ T ≤ +85˚C		75		ppm/˚C
f_A	Astable Frequency	SW 1, 3 Closed, V_S = 12V	4.0	4.8	5.6	kHz
f_{MAX}	Maximum Frequency	Max. Freq. Test Circuit, V_S = 5V		3.0		MHz
t_R, t_F	Output Rise and Fall Times	Max. Freq. Test Circuit V_S = 5V, C_L = 10 pF		15		ns
t_{PD}	Trigger Propagation Delay	V_S = 5V, Measure Delay from Trigger to Output		100		ns

Note 1: All voltages are measured with respect to the ground pin, unless otherwise specified.

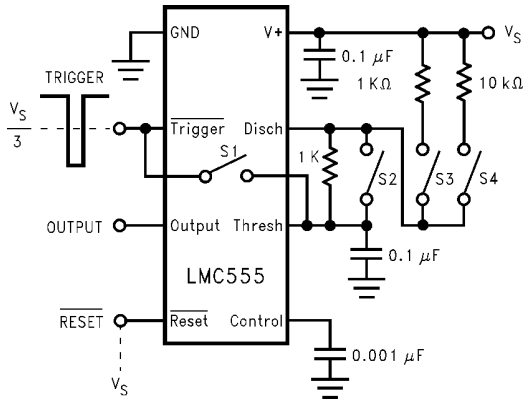
Note 2: Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is functional, but do not guarantee specific performance limits. Electrical Characteristics state DC and AC electrical specifications under particular test conditions which guarantee specific performance limits. This assumes that the device is within the Operating Ratings. Specifications are not guaranteed for parameters where no limit is given, however, the typical value is a good indication of device performance.

Note 3: See AN-450 for other methods of soldering surface mount devices, and also AN-1112 for micro SMD considerations.

Note 4: If the $\overline{\text{RESET}}$ pin is to be used at temperatures of −20˚C and below V_S is required to be 2.0V or greater.

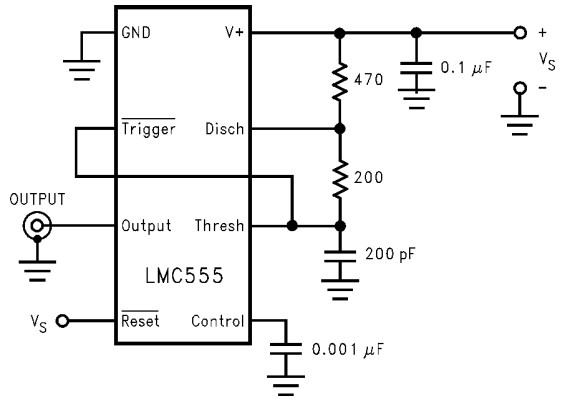
Note 5: For device pinout please refer to table 1

Test Circuit (Note 5)



00866902

Maximum Frequency Test Circuit (Note 5)



00866903

TABLE 1. Package Pinout Names vs. Pin Function

Pin Function	Package Pin numbers	
	8-Pin SO, MSOP, and MDIP	8-Bump micro SMD
GND	1	A3
$\overline{\text{Trigger}}$	2	B3
Output	3	C3
$\overline{\text{Reset}}$	4	C2
Control Voltage	5	C1
Threshold	6	B1
Discharge	7	A1
V^+	8	A2

Application Information

MONOSTABLE OPERATION

In this mode of operation, the timer functions as a one-shot (*Figure 1*). The external capacitor is initially held discharged by internal circuitry. Upon application of a negative trigger pulse of less than 1/3 V_S to the $\overline{\text{Trigger}}$ terminal, the flip-flop is set which both releases the short circuit across the capacitor and drives the output high.

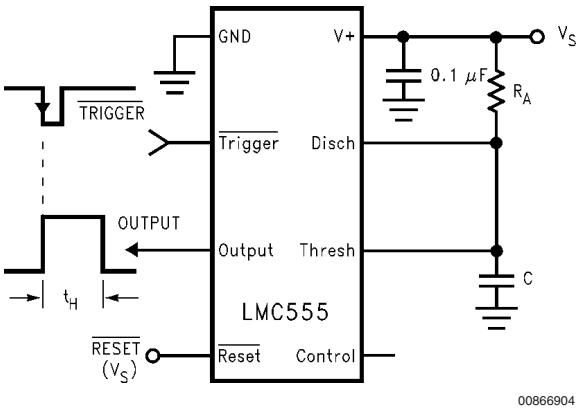
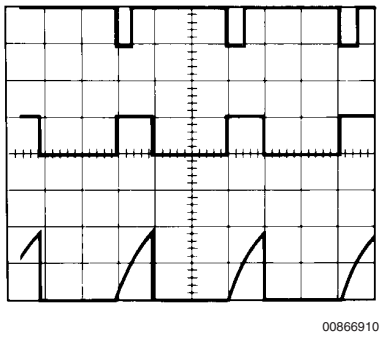


FIGURE 1. Monostable (One-Shot)

The voltage across the capacitor then increases exponentially for a period of $t_H = 1.1\ R_AC$, which is also the time that the output stays high, at the end of which time the voltage equals 2/3 V_S. The comparator then resets the flip-flop which in turn discharges the capacitor and drives the output to its low state. *Figure 2* shows the waveforms generated in this mode of operation. Since the charge and the threshold level of the comparator are both directly proportional to supply voltage, the timing internal is independent of supply.



V_{CC} = 5V Top Trace: Input 5 V/Div.
TIME = 0.1 ms/Div. Middle Trace: Output 5 V/Div.
R_A = 9.1 kΩ Bottom Trace: Capacitor Voltage 2 V/Div.
C = 0.01 µF

FIGURE 2. Monostable Waveforms

Reset overrides Trigger, which can override threshold. Therefore the trigger pulse must be shorter than the desired t_H. The minimum pulse width for the Trigger is 20ns, and it is 400ns for the Reset. During the timing cycle when the output is high, the further application of a trigger pulse will not effect the circuit so long as the trigger input is returned high at least 10µs before the end of the timing interval. However the circuit can be reset during this time by the application of a negative pulse to the reset terminal. The output will then remain in the low state until a trigger pulse is again applied.

When the reset function is not use, it is recommended that it be connected to V_+ to avoid any possibility of false triggering. *Figure 3* is a nomograph for easy determination of RC values for various time delays.

Note: In monstable operation, the trigger should be driven high before the end of timing cycle.

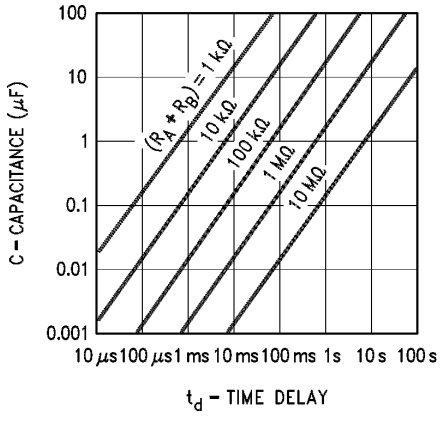


FIGURE 3. Time Delay

ASTABLE OPERATION

If the circuit is connected as shown in *Figure 4* ($\overline{\text{Trigger}}$ and Threshold terminals connected together) it will trigger itself and free run as a multivibrator. The external capacitor charges through $R_A + R_B$ and discharges through R_B. Thus the duty cycle may be precisely set by the ratio of these two resistors.

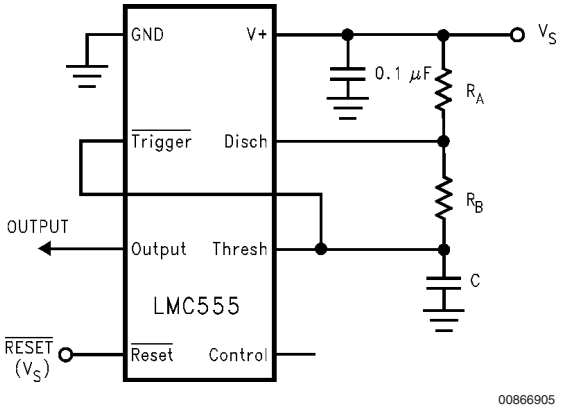
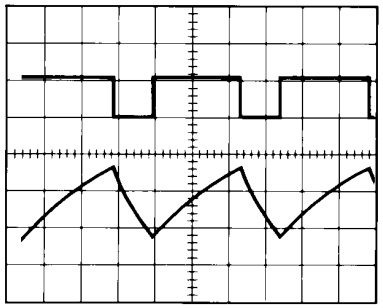


FIGURE 4. Astable (Variable Duty Cycle Oscillator)

In this mode of operation, the capacitor charges and discharges between 1/3 V_S and 2/3 V_S. As in the triggered mode, the charge and discharge times, and therefore the frequency are independent of the supply voltage.

Figure 5 shows the waveform generated in this mode of operation.

Application Information (Continued)



00866912

V_{CC} = 5V Top Trace: Output 5 V/Div.
TIME = 20 µs/Div. Bottom Trace: Capacitor Voltage 1 V/Div.
R_A = 3.9 kΩ
R_B = 9 kΩ
C = 0.01 µF

FIGURE 5. Astable Waveforms

The charge time (output high) is given by

$$t_1 = 0.693\ (R_A + R_B)C$$

And the discharge time (output low) by:

$$t_2 = 0.693\ (R_B)C$$

Thus the total period is:

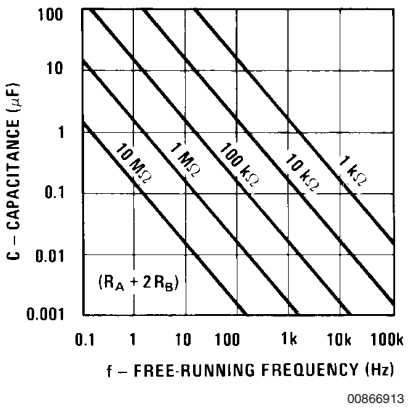
$$T = t_1 + t_2 = 0.693\ (R_A + R_B)C$$

The frequency of oscillation is:

$$f = \frac{1}{T} = \frac{1.44}{(R_A + 2R_B)C}$$

Figure 6 may be used for quick determination of these RC Values. The duty cycle, as a fraction of total period that the output is low, is:

$$D = \frac{R_B}{R_A + 2R_B}$$

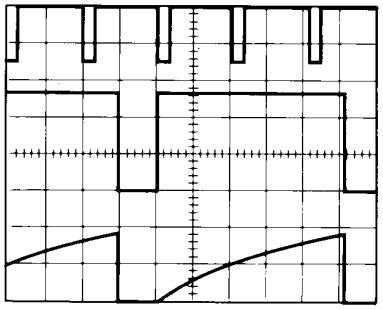


00866913

FIGURE 6. Free Running Frequency

FREQUENCY DIVIDER

The monostable circuit of *Figure 1* can be used as a frequency divider by adjusting the length of the timing cycle. *Figure 7* shows the waveforms generated in a divide by three circuit.



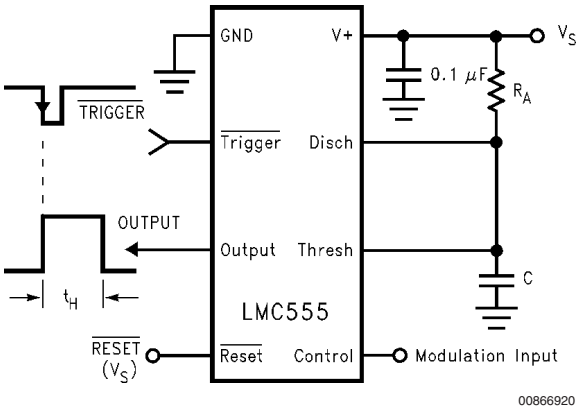
00866914

V_{CC} = 5V Top Trace: Input 4 V/Div.
TIME = 20 µs/Div. Middle Trace: Output 2 V/Div.
R_A = 9.1 kΩ Bottom Trace: Capacitor 2 V/Div.
C = 0.01 µF

FIGURE 7. Frequency Divider Waveforms

PULSE WIDTH MODULATOR

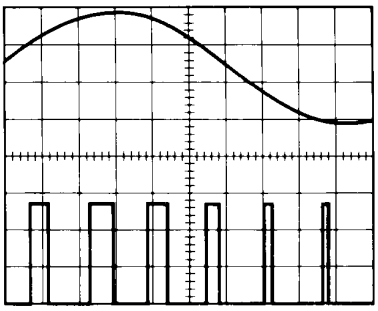
When the timer is connected in the monostable mode and triggered with a continuous pulse train, the output pulse width can be modulated by a signal applied to the Control Voltage Terminal. *Figure 8* shows the circuit, and in *Figure 9* are some waveform examples.



00866920

FIGURE 8. Pulse Width Modulator

Application Information (Continued)



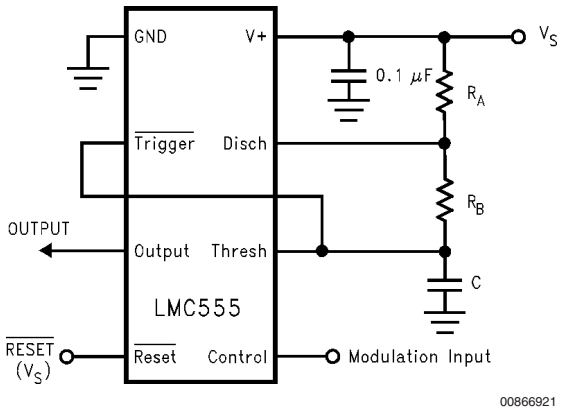
00866915

V_{CC} = 5V Top Trace: Modulation 1 V/Div.
TIME = 0.2 ms/Div. Bottom Trace: Output Voltage 2 V/Div.
R_A = 9.1 kΩ
C = 0.01 µF

FIGURE 9. Pulse Width Modulator Waveforms

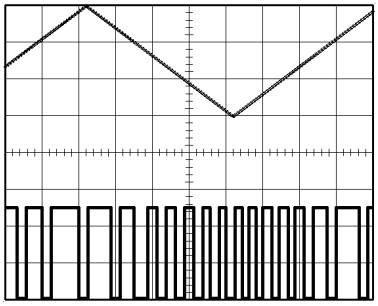
PULSE POSITION MODULATOR

This application uses the timer connected for astable operation, as in *Figure 10*, with a modulating signal again applied to the control voltage terminal. The pulse position varies with the modulating signal, since the threshold voltage and hence the time delay is varied. *Figure 11* shows the waveforms generated for a triangle wave modulation signal.



00866921

FIGURE 10. Pulse Position Modulator



00866916

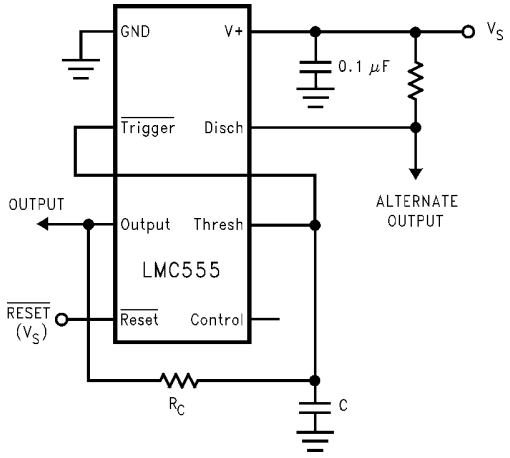
V_{CC} = 5V Top Trace: Modulation Input 1 V/Div.
TIME = 0.1 ms/Div. Bottom Trace: Output Voltage 2 V/Div.
R_A = 3.9 kΩ
R_B = 3 kΩ
C = 0.01 µF

FIGURE 11. Pulse Position Modulator Waveforms

50% DUTY CYCLE OSCILLATOR

The frequency of oscillation is

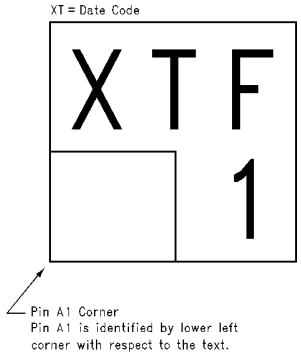
$$f = 1/(1.4\ R_C C)$$



00866906

FIGURE 12. 50% Duty Cycle Oscillator

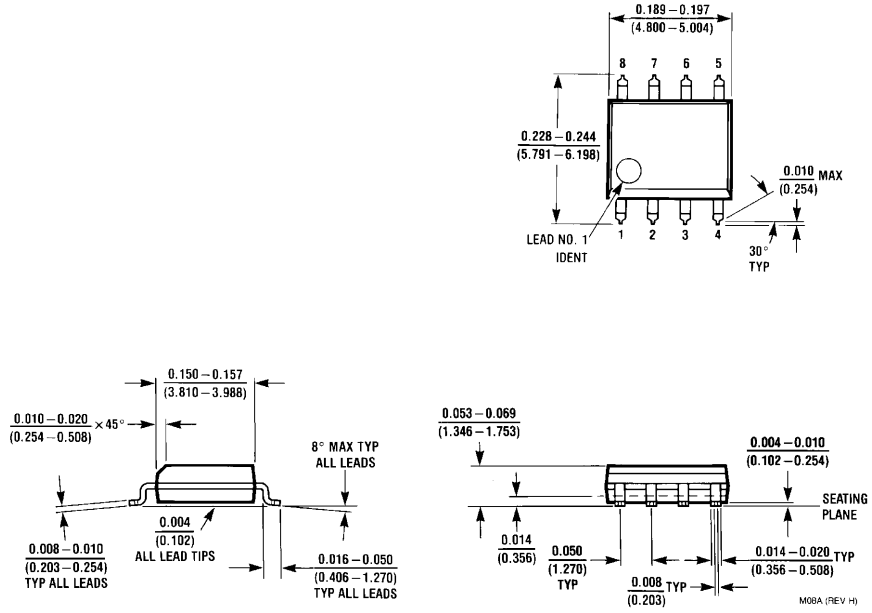
micro SMD Marking Orientation
Top View



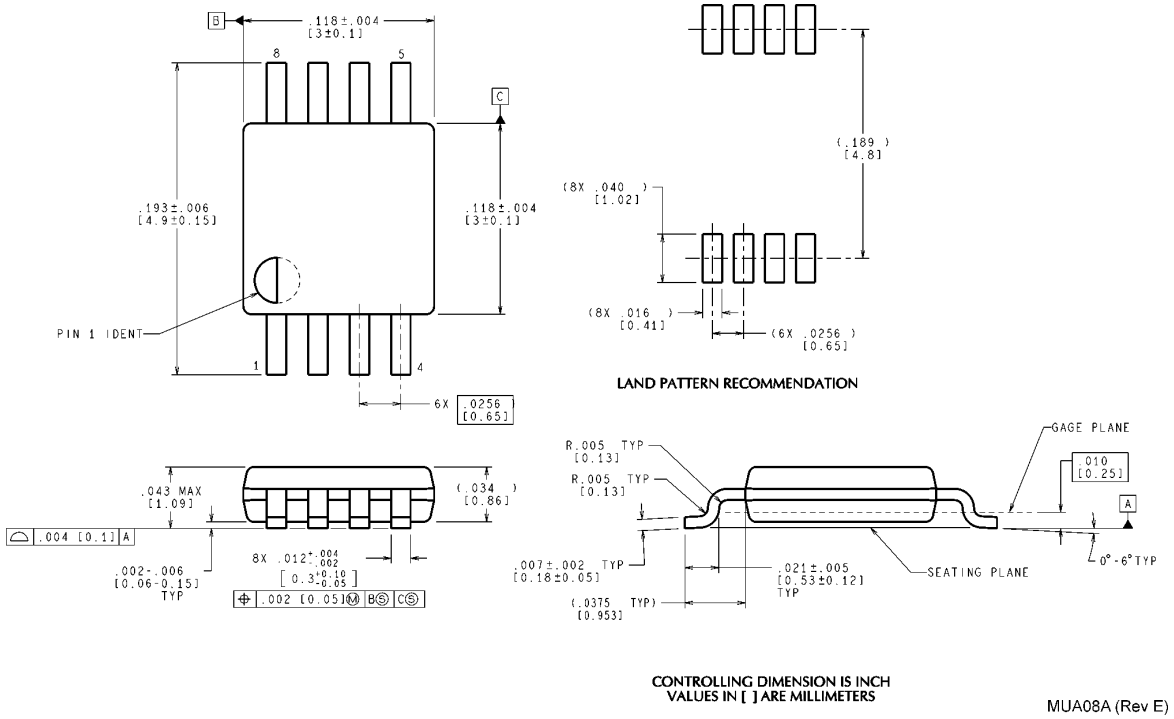
00866923

Bumps are numbered counter-clockwise

Physical Dimensions inches (millimeters) unless otherwise noted

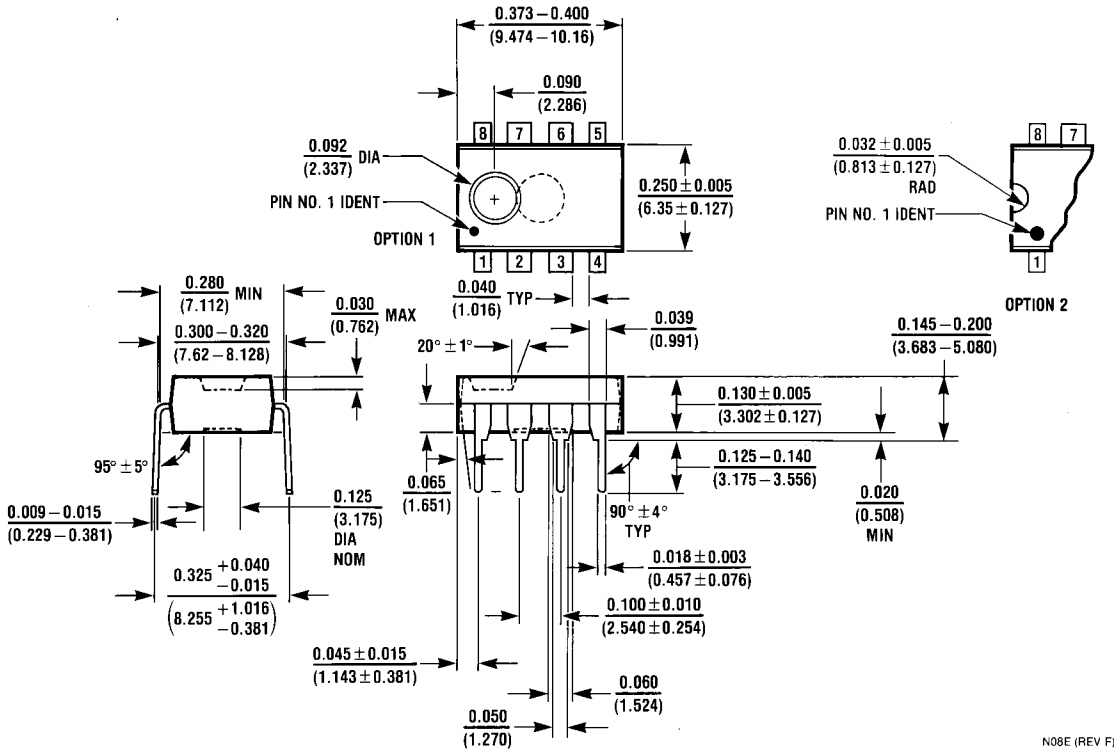


Molded Small Outline (SO) Package (M)
NS Package Number M08A



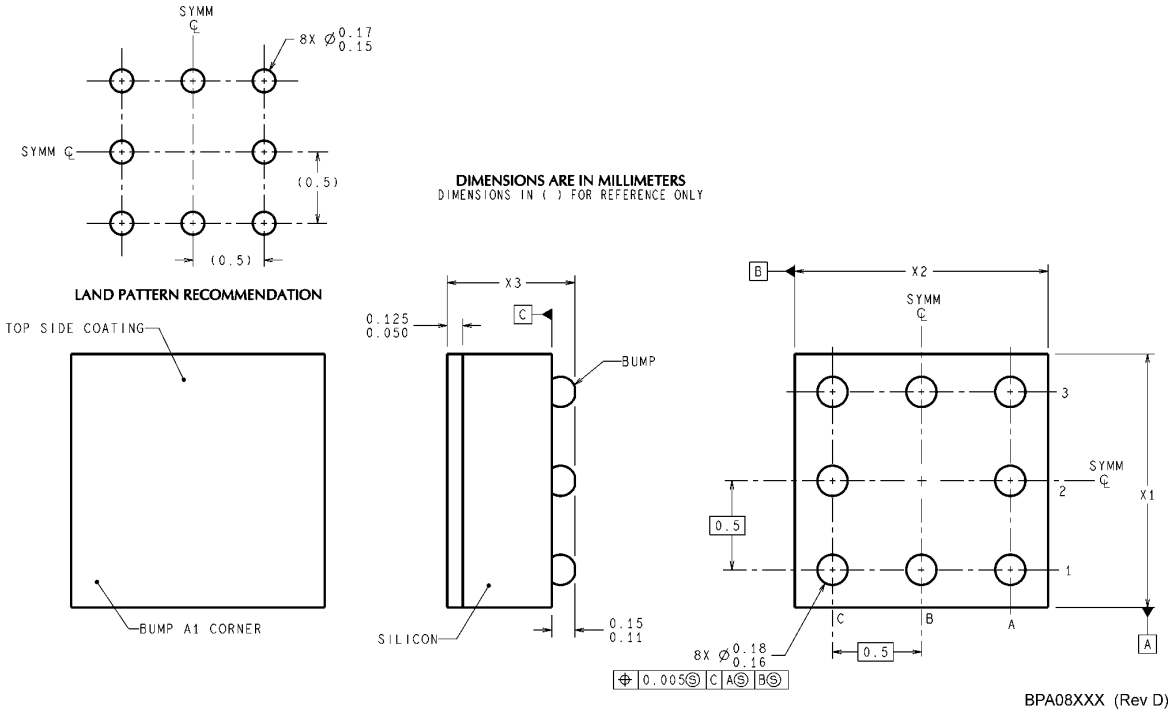
8-Pin (0.118” Wide) Molded Mini Small Outline Package
NS Package Number MUA08A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



Molded Dual-in-line Package (N)
NS Package Number N08E

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



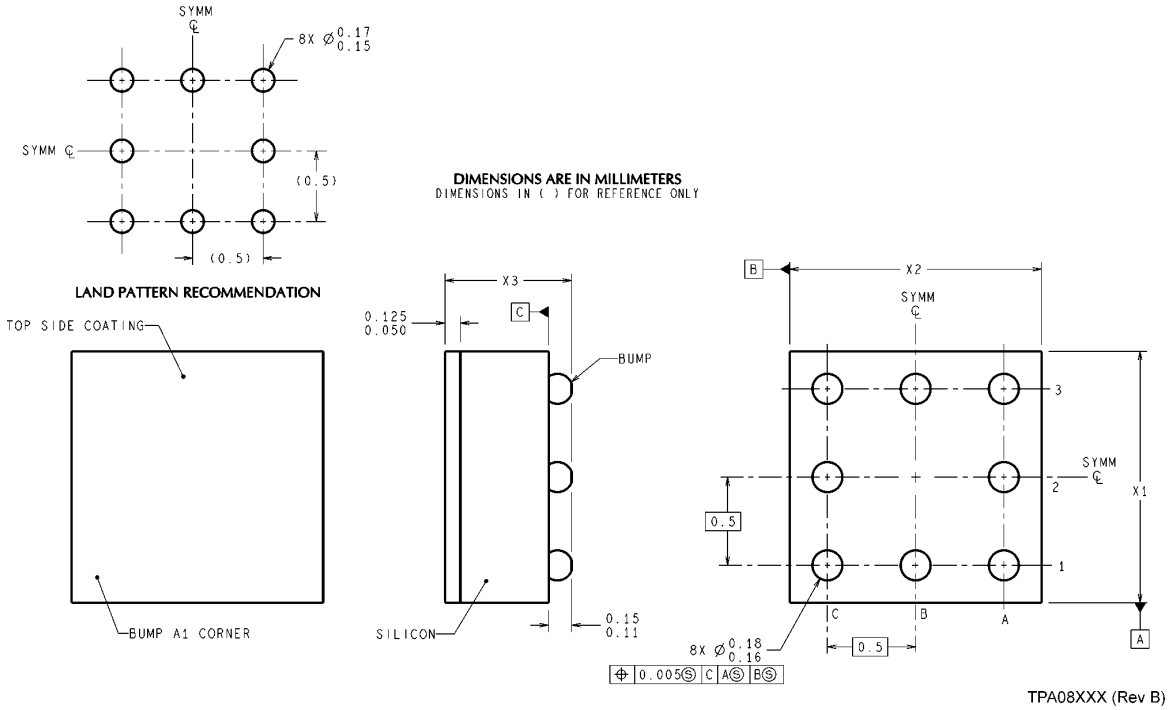
BPA08XXX (Rev D)

NOTES: UNLESS OTHERWISE SPECIFIED

1. EPOXY COATING
2. 63Sn/37Pb EUTECTIC BUMP
3. RECOMMEND NON-SOLDER MASK DEFINED LANDING PAD.
4. PIN A1 IS ESTABLISHED BY LOWER LEFT CORNER WITH RESPECT TO TEXT ORIENTATION. REMAINING PINS ARE NUMBERED COUNTERCLOCKWISE.
5. XXX IN DRAWING NUMBER REPRESENTS PACKAGE SIZE VARIATION WHERE X1 IS PACKAGE WIDTH, X2 IS PACKAGE LENGTH AND X3 IS PACKAGE HEIGHT.
6. REFERENCE JEDEC REGISTRATION MO-211, VARIATION BC.

8-Bump micro SMD Package
NS Package Number BPA08EFB
$X_1 = 1.387$ $X_2 = 1.412$ $X_3 = 0.850$

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



TPA08XXX (Rev B)

NOTES: UNLESS OTHERWISE SPECIFIED

1. EPOXY COATING
2. FOR SOLDER BUMP COMPOSITION, SEE “SOLDER INFORMATION” IN THE PACKAGING SECTION OF THE NATIONAL SEMICONDUCTOR WEB PAGE (www.national.com).
3. RECOMMEND NON-SOLDER MASK DEFINED LANDING PAD.
4. PIN A1 IS ESTABLISHED BY LOWER LEFT CORNER WITH RESPECT TO TEXT ORIENTATION.
5. XXX IN DRAWING NUMBER REPRESENTS PACKAGE SIZE VARIATION WHERE X1 IS PACKAGE WIDTH, X2 IS PACKAGE LENGTH AND X3 IS PACKAGE HEIGHT.
6. REFERENCE JEDEC REGISTRATION MO-211, VARIATION BC.

8-Bump micro SMD Package
NS Package Number TPA08EFA
$X_1 = 1.387$ $X_2 = 1.412$ $X_3 = 0.500$

National Semiconductor
Americas Customer
Support Center
Email: new.feedback@nsc.com
Tel: 1-800-272-9959

National Semiconductor
Europe Customer Support Center
Fax: +49 (0) 180-530 85 86
Email: europe.support@nsc.com
Deutsch Tel: +49 (0) 69 9508 6208
English Tel: +44 (0) 870 24 0 2171
Français Tel: +33 (0) 1 41 91 8790

National Semiconductor
Asia Pacific Customer
Support Center
Email: ap.support@nsc.com

National Semiconductor
Japan Customer Support Center
Fax: 81-3-5639-7507
Email: jpn.feedback@nsc.com

LMC555 - CMOS Timer

RoHS Compliant

Datasheet | Packaging | Samples & Pricing | Reliability | Design Tools | Knowledge Base

Features

- Less than 1 mW typical power dissipation at 5V supply
- 3 MHz astable frequency capability
- 1.5V supply operating voltage guaranteed
- Output fully compatible with TTL and CMOS logic at 5V supply
- Tested to -10 mA, +50 mA output current levels
- Reduced supply current spikes during output transitions
- Extremely low reset, trigger, and threshold currents
- Excellent temperature stability
- Pin-for-pin compatible with 555 series of timers
- Available in 8-pin MSOP Package and 8-Bump micro SMD package

General Description

The LMC555 is a CMOS version of the industry standard 555 series general purpose timers. More...

Typical Application

See Datasheet for Application Information

Parametric Table expand

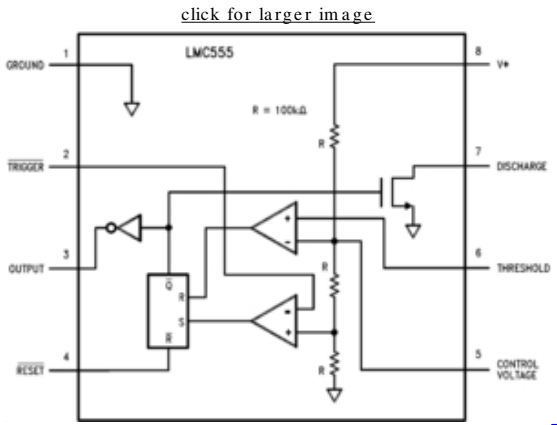
Temperature Min	-40 deg C
Temperature Max	85 deg C

Additional Resources

Design Tools (see below)

Connection Diagram

click for larger image



Datasheet

RoHS Compliance Information	Size in Kbytes	Date	
LMC555 CMOS Timer	767 Kbytes	25-May-06	View Online Download
LMC555 CMOS Timer (**Japanese**) 本サイトの日本語版データシートは最新版ではない場合があります。ご検討 およびご採用に当たっては、最新の英語版データシートを必ずご確認ください。	513 Kbytes		ダウンロード
LMC555 Mil-Aero Datasheet MNLMC555-X	160 Kbytes		Download

If you have trouble printing or viewing PDF file(s), see Printing Problems.

Package Availability, Models, Samples & Pricing

Part Number	Package							Factory Lead Time		Models	Samples & Electronic Orders	Budgetary Pricing		Std Pack Size	Package Marking Format
	Type	Pins	Spec.	MSL Rating	Peak Reflow	RoHS Report	CAD Symbols	Weeks	Qty			Qty	$US each		
LMC555CBPX	MICRO SMD	8	STD	1	260	RoHS	N/A	Lifetime buy 12 weeks	15000	N/A	Buy Now	1K+	$0.48	reel of 3000	XVF I 1
LMC555CM	SOIC NARROW	8	STD NOPB	1 1	235 260	RoHS	N/A	Full production 6 weeks	5000	N/A	Samples Buy Now	1K+	$0.43	rail of 95	NSZXTT LMC 555CM
LMC555CMX	SOIC NARROW	8	STD NOPB	1 1	235 260	RoHS	N/A	Full production 6 weeks	5000	N/A	Buy Now	1K+	$0.43	reel of 2500	NSZXTT LMC 555CM
LMC555CMM	MINI SOIC	8	STD NOPB	1 1	260 260	RoHS	N/A	Full production 8 weeks	5000	N/A	Samples Buy Now	1K+	$0.50	reel of 1000	ZXTT ZC5
LMC555CMMX	MINI SOIC	8	STD NOPB	1 1	260 260	RoHS	N/A	Full production 8 weeks	7500	N/A	Buy Now	1K+	$0.50	reel of 3500	ZXTT ZC5

LMC555CN	MDIP	8	STD NOPB	1 1	NA NA	RoHS	N/A	Full production 6 weeks	3000	N/A	Samples Buy Now	1K+	$0.54	rail of 40	NSUZXYTT LMC 555CN
LMC555CTP	MICRO SMD	8	NOPB	1	260	RoHS	N/A	Full production 6 weeks	N/A	N/A	Samples Buy Now	1K+	$0.59	reel of 250	XVF I 02
LMC555CTPX	MICRO SMD	8	NOPB	1	260	RoHS	N/A	Full production 6 weeks	N/A	N/A	Buy Now	1K+	$0.59	reel of 3000	XVF I 02
LMC555 MDA	Unpackaged Die							Full production N/A	N/A	N/A			CALL	tray of N/A	-
LMC555 MD8	Unpackaged Die							Full production N/A	N/A	N/A			CALL	tray of N/A	-
5962-8950305PA (LMC555J/883)	CERDIP	8				RoHS	N/A	Obsolete 8 weeks	500	N/A	Buy Now	50+	$11.70	rail of 40	NSZSSXXYYA LMC555J/883 Q 5962-8950305PA

Obsolete Parts

Obsolete Part	Alternate Part or Supplier	Source	Last Time Buy Date
LMC555CBP	NONE	NONE	07/24/2009
LMC555CBPX	NONE	NONE	07/24/2009
LMC555G-R DWF	NONE	NONE	04/04/95
LMC555H/883	LMC555J/883	NATIONAL SEMICONDUCTOR	09/08/98
LMC555J/883	LM555J/883	NONE	12/03/2008

General Description

The LMC555 is a CMOS version of the industry standard 555 series general purpose timers. In addition to the standard package (SOIC, MSOP, and MDIP) the LMC555 is also available in a chip sized package (8 Bump micro SMD) using National's micro SMD package technology. The LMC555 offers the same capability of generating accurate time delays and frequencies as the LM555 but with much lower power dissipation and supply current spikes. When operated as a one-shot, the time delay is precisely controlled by a single external resistor and capacitor. In the stable mode the oscillation frequency and duty cycle are accurately set by two external resistors and one capacitor. The use of National Semiconductor's LMCMOS™ process extends both the frequency range and low supply capability.

Reliability Metrics

Part Number	Process	EFR Reject	EFR Sample Size	PPM *	LTA Rejects	LTA Device Hours	FITS	MTTF (Hours)
LMC555 MD8	CMOS	0	16925	0	0	2065000	2	585949388
LMC555 MDA	P2CMOS	0	45010	0	1	3767500	3	484371054
LMC555CBPX	P2CMOS	0	45010	0	1	3767500	3	484371054
LMC555CM	P2CMOS	0	45010	0	1	3767500	3	484371054
LMC555CMM	P2CMOS	0	45010	0	1	3767500	3	484371054
LMC555CMMX	P2CMOS	0	45010	0	1	3767500	3	484371054
LMC555CMX	P2CMOS	0	45010	0	1	3767500	3	484371054
LMC555CN	P2CMOS	0	45010	0	1	3767500	3	484371054
LMC555CTP	P2CMOS	0	45010	0	1	3767500	3	484371054
LMC555CTPX	P2CMOS	0	45010	0	1	3767500	3	484371054
LMC555J/883	CMOS	0	16925	0	0	2065000	2	585949388

Note: The Early Failure Rates were calculated as point estimates. The Long Term Failure Rates were calculated at 60% confidence using the Arrhenius equation at 0.7eV activation energy and derating the assumed stress temperature of 150°C to an application temperature of 55°C.

For more information on Reliability Metrics, please click here.

Design Tools

Title	Size in Kbytes	Date			
LMC555CBP Micro SMD Qualification Package	4172 Kbytes	17-Apr-2000	View Online	Download	

If you have trouble printing or viewing PDF file(s), see Printing Problems.

Application Notes

Title	Size in Kbytes	Date	
AN-828: Application Note 828 Increasing the High Speed Torque of Bipolar Stepper Motors	808 Kbytes	1-Oct-02	Download
AN-828 (Japanese): Application Note 828 Increasing the High Speed Torque of Bipolar Stepper Motors 本サイトの日本語アプリケーション・ノートは最新版でない場合があります。ご検討および ご採用にあたっては、必ず最新の英語版アプリケーション・ノートをご確認ください。	362 Kbytes		ダウンロード
AN-681: PC Mouse Implementation Using COP800	525 Kbytes	5-Aug-95	Download
AN-460: Application Note 460 LM34/LM35 Precision Monolithic Temperature Sensors	306 Kbytes	20-Sep-02	Download

AN-460 (Japanese): Application Note 460 LM34/LM35 Precision Monolithic Temperature Sensors 本サイトの日本語アプリケーション・ノートは最新版でない場合があります。ご検討および ご採用にあたっては、必ず最新の英語版アプリケーション・ノートをご確認ください。	322 Kbytes		ダウンロード

If you have trouble printing or viewing PDF file(s), see Printing Problems.

[Information as of 22-Dec-2008]